TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG02FU

2 Input NOR Gate

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

at V_{CC} = 3.0 V

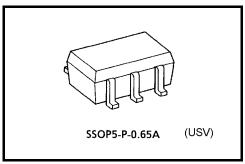
• High-speed operation: t_{pd} = 2.4 ns (typ.)

at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

Operating voltage range: V_{CC} = 0.9~3.6 V

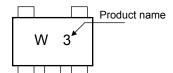
• 5.5-V tolerant inputs.

• 3.6-V power down protection output.

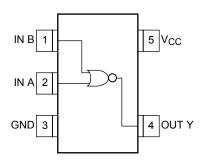


Weight: 0.006 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Value | Unit | | | |
|------------------------------------|------------------|--------------------------------------|------|--|--|--|
| Power supply voltage | V _{CC} | -0.5~4.6 | V | | | |
| DC input voltage | V _{IN} | -0.5~7.0 | V | | | |
| DC custout voltage | V | -0.5~ 4.6 (Note 1) | | | | |
| DC output voltage | Vout | -0.5~ V _{CC} + 0.5 (Note 2) | V | | | |
| Input diode current | I _{IK} | -20 | mA | | | |
| Output diode current | lok | -20 (Note 3) | mA | | | |
| DC output current | I _{OUT} | ±25 | mA | | | |
| DC V _{CC} /ground current | I _{CC} | ±50 | mA | | | |
| Power dissipation | PD | 200 | mW | | | |
| Storage temperature | T _{stg} | -65~150 | °C | | | |

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0V

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: VOUT < GND

IEC Logic Symbol



Truth Table

| Α | В | Υ |
|---|---|---|
| L | L | Н |
| L | Н | L |
| Н | L | L |
| Н | Н | L |

Operating Ranges

| Characteristics | Symbol | Value | Unit | | |
|--------------------------|----------------------------------|----------------------------|------|--|--|
| Power supply voltage | V _{CC} | 0.9~3.6 | V | | |
| Input voltage | V _{IN} | 0~5.5 | V | | |
| Output voltage | Vour | 0~3.6 (Note 4) | V | | |
| | V _{OUT} | 0~V _{CC} (Note 5) | | | |
| Output Current | | ±8.0 (Note 6) | | | |
| | 1 | ±4.0 (Note 7) | - mA | | |
| | | ±3.0 (Note 8) | | | |
| | I _{OH} /I _{OL} | ±1.7 (Note 9) | | | |
| | | ±0.3 (Note 10) | | | |
| | | ±0.02 (Note 11) | | | |
| Operating temperature | T _{opr} | -40~85 | °C | | |
| Input rise and fall time | dt/dV | 0~10 (Note 12) | ns/V | | |

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Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

Note 6: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 7: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: V_{CC} = 1.4~1.6 V

Note 10: V_{CC} = 1.1~1.3 V

Note 11: $V_{CC} = 0.9 V$

Note 12: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

DC Electrical Characteristics

| Characteristics | aracteristics Symbol Test Condition | | | Ta = 25°C | | | Ta = -40~85°C | | Unit | |
|------------------------------|-------------------------------------|---|----------------------------|------------------------|--------------------------|------|---------------------------|--------------------------|------------------------|-------|
| Sharaotoribuos Symbol | | rest Condition | | V _{CC} (V) | Min | Тур. | Max | Min | Max | Offic |
| High-level VIH input voltage | | | 0.9 | V _{CC} | | _ | V _{CC} | _ | | |
| | | _ | | 1.1~1.3 | V _{CC} × 0.7 | | _ | V _{CC} × 0.7 | | _ |
| | V _{IH} | | | 1.4~1.6 | V _{CC} × 0.65 | | _ | V _{CC} × 0.65 | | V |
| | | | 1.65~1.95 | V _{CC} × 0.65 | | _ | V _{CC} × 0.65 | | | |
| | | | 2.3~2.7 | 1.7 | | _ | 1.7 | _ | | |
| | | | | 3.0~3.6 | 2.0 | | | 2.0 | _ | |
| | | | | 0.9 | _ | _ | GND | _ | GND | |
| | | _ | | 1.1~1.3 | | | V _{CC} × 0.3 | _ | V _{CC} × 0.3 | ٧ |
| Low-level | V _{IL} | | | 1.4~1.6 | | | V _{CC} × 0.35 | _ | V _{CC} × 0.35 | |
| input voltage | | | | 1.65~1.95 | ١ | I | V _{CC} × 0.35 | | V _{CC} × 0.35 | |
| | | | | 2.3~2.7 | | | 0.7 | | 0.7 | |
| | | | | 3.0~3.6 | _ | | 0.8 | | 0.8 | |
| | | DH VIN = VIL | I _{OH} =-0.02 mA | 0.9 | 0.75 | _ | _ | 0.75 | _ | V |
| High-level VOH | | | $I_{OH} = -0.3 \text{ mA}$ | 1.1~1.3 | V _{CC} × 0.75 | | _ | V _{CC} × 0.75 | _ | |
| | V _{OH} | | $I_{OH} = -1.7 \text{ mA}$ | 1.4~1.6 | V _{CC} × 0.75 | | _ | V _{CC} × 0.75 | _ | |
| | | | $I_{OH} = -3.0 \text{ mA}$ | 1.65~ 1.95 | V _{CC} -0.45 | _ | _ | V _{CC} -0.45 | _ | |
| | | | $I_{OH} = -4.0 \text{ mA}$ | 2.3~2.7 | 2.0 | | | 2.0 | _ | |
| | | | $I_{OH} = -8.0 \text{ mA}$ | 3.0~3.6 | 2.48 | | | 2.48 | _ | |
| | | V _{IN} = V _{IH} or V _{IL} | $I_{OL} = 0.02 \text{ mA}$ | 0.9 | _ | _ | 0.1 | _ | 0.1 | ٧ |
| Low-level Voltage | | | I _{OL} = 0.3 mA | 1.1~1.3 | _ | _ | V _{CC} × 0.25 | _ | V _{CC} × 0.25 | |
| | V _{OL} | | I _{OL} = 1.7 mA | 1.4~1.6 | | | V _{CC} × 0.25 | _ | V _{CC} × 0.25 | |
| | | | I _{OL} = 3.0 mA | 1.65~ 1.95 | _ | _ | 0.45 | _ | 0.45 | |
| | | | I _{OL} = 4.0 mA | 2.3~2.7 | _ | | 0.4 | _ | 0.4 | |
| | | | I _{OL} = 8.0 mA | 3.0~3.6 | _ | _ | 0.4 | _ | 0.4 | |
| Input leakage current | I _{IN} | V _{IN} = 0~5.5V | | 0~3.6 | | _ | ±0.1 | _ | ±1.0 | μА |
| Power off leakage current | l _{OFF} | V _{IN} = 0~5.5V V _{OUT} = 0~3.6V | | 0 | | | 1.0 | _ | 10.0 | μА |
| Quiescent supply current | Icc | V _{IN} = V _{CC} or GND | | 3.6 | _ | | 1.0 | _ | 10.0 | μΑ |

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AC Electrical Characteristics (input $t_r = t_f = 3$ ns)

| Characteristics | Symbol Test Condition | | Ta = 25°C | | Ta = -40~85°C | | Unit | | |
|-------------------------------|--------------------------------------|--|---------------------|-----|---------------|------|------|------|-------|
| Characteristics | Symbol | rest Condition | V _{CC} (V) | Min | Тур. | Max | Min | Max | Offic |
| | | $\begin{array}{l} C_L = 10 \ pF, \\ R_L = 1 \ M\Omega \end{array}$ | 0.9 | _ | 17.0 | _ | _ | _ | |
| | | | 1.1~1.3 | _ | 8.8 | 18.4 | 1.0 | 34.2 | |
| | | | 1.4~1.6 | _ | 5.0 | 8.5 | 1.0 | 10.0 | |
| | | | 1.65~ 1.95 | | 3.8 | 6.2 | 1.0 | 6.7 | |
| | | | 2.3~2.7 | _ | 2.7 | 3.9 | 1.0 | 4.4 | |
| Propagation delay time | | | 3.0~3.6 | _ | 2.1 | 3.1 | 1.0 | 3.7 | |
| | | $C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$ | 0.9 | _ | 20.7 | _ | _ | _ | |
| | ^t РLН ^t РНL | | 1.1~1.3 | _ | 10.6 | 21.5 | 1.0 | 37.2 | |
| | | | 1.4~1.6 | _ | 5.9 | 9.3 | 1.0 | 11.2 | |
| | | | 1.65~ 1.95 | _ | 4.5 | 6.9 | 1.0 | 7.1 | ns |
| | | | 2.3~2.7 | _ | 3.0 | 4.4 | 1.0 | 5.0 | |
| | | | 3.0~3.6 | _ | 2.4 | 3.4 | 1.0 | 3.9 | |
| | | $C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$ | 0.9 | _ | 29.6 | _ | _ | _ | |
| | | | 1.1~1.3 | _ | 14.8 | 29.6 | 1.0 | 56.0 | |
| | | | 1.4~1.6 | _ | 8.0 | 13.1 | 1.0 | 15.9 | |
| | | | 1.65~ 1.95 | _ | 6.0 | 9.2 | 1.0 | 9.6 | |
| | | | 2.3~2.7 | _ | 3.9 | 5.7 | 1.0 | 6.1 | |
| | | | 3.0~3.6 | _ | 3.0 | 4.4 | 1.0 | 4.8 | |
| Input capacitance | C _{IN} | _ | 3.6 | _ | 3 | _ | _ | _ | pF |
| Power dissipation capacitance | C _{PD} | (Note 13) | 0.9~3.6 | — | 6 | | | _ | pF |

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

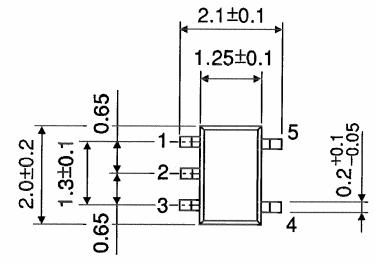
Average operating current can be obtained by the equation:

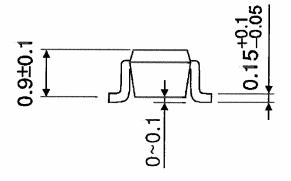
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

TOSHIBA

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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